

super-QR/PSR[™] CV/CC Controller

FEATURES

- **♦** Easily Meet EPS Level 6
- ◆ Less than 75mW Standby Power
- ◆ Proprietary super-QR/PSRTM (Quasi-Resonant & Primary Side Regulation) Control for High Efficiency and Low EMI
- ♦ ±5% CC and CV Precision
- **♦** Proprietary Cable Drop Compensation
- **♦** Smart Output Short Protection
- **♦** Cycle-by-Cycle Current Limiting
- **♦** Built-in Leading Edge Blanking (LEB)
- **♦** Pin Floating Protection
- ♦ Built-in Soft Start
- Output Over Voltage Protection
- ◆ VDD OVP & Clamp
- ♦ VDD Under Voltage Lockout (UVLO)

APPLICATIONS

- Battery chargers for cellular phones, cordless phones, PDA, digital cameras, etc
- **♦** Replaces linear transformer and RCC SMPS
- ♦ AC/DC LED lighting

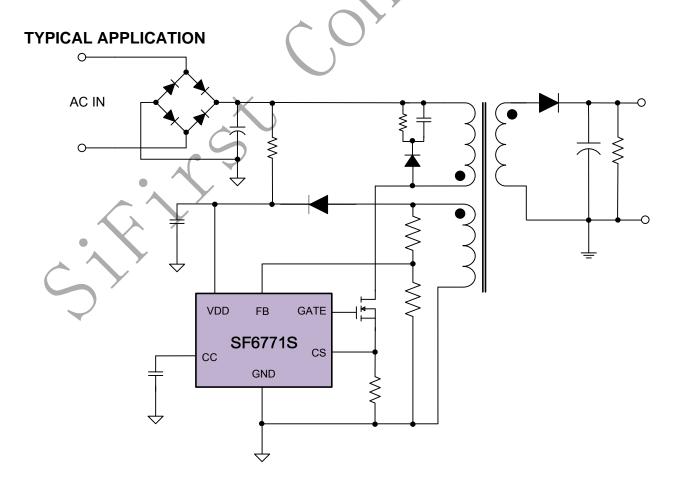
GENERAL DESCRIPTION

SF6771S is a high performance, highly integrated QR (Quasi Resonant Mode) and Primary Side Regulation (PSR) controller for offline small power converter applications.

SF6771S has proprietary *super-QR/PSRTM* control for high efficiency and low EMI. The standby power is less than 75mW @230VAC. Thus, the IC can meet EPS Level 6 energy standard easily. The IC also has built-in cable drop compensation function, which can provide excellent CV performance.

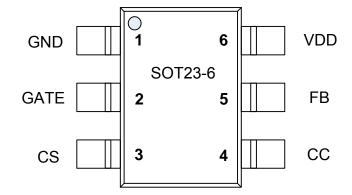
SF6771S integrates functions and protections of Under Voltage Lockout (UVLO), VDD Over Voltage Protection (VDD OVP), Soft Start, Cycle-by-cycle Current Limiting (OCP), Pin Floating Protection, Gate Clamping, VDD Clamping.

SF6771S is available in SOT23-6 package.





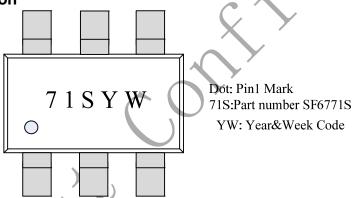
Pin Configuration



Ordering Information

Part Number	Top Mark	Pacl	kage	Tape & Reel
SF6771SLGT	.71SYW	SOT23-6	Green	Yes

Marking Information

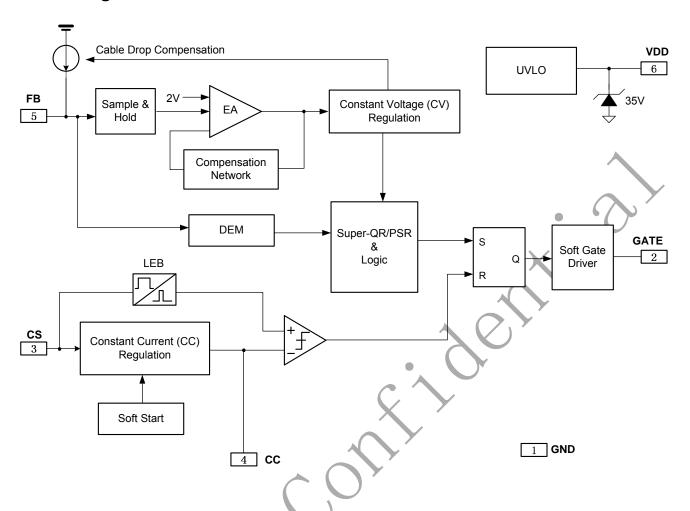


Pin Description

Pin Num	Pin Name	I/O	Description
1	GND	Р	Ground
2	GATE	0	Totem-pole gate driver output to drive the external MOSFET.
3	CS	1	Current sense pin.
4	CC	0	Connect a capacitor between this pin and GND for CC regulation.
5	FB	1	System feedback pin. This control input regulates both the output voltage
			in CV mode and output current in CC mode based on the flyback voltage
			of the auxiliary winding.
6	VDD	Р	IC power supply pin.



Block Diagram



Absolute Maximum Ratings (Note 1)

Parameter	Value	Unit
VDD DC Supply Voltage	35	V
VDD DC Clamp Current	10	mA
GATE pin	20	V
CC, CS voltage range	-0.3 to 7	V
FB voltage range	-0.7 to 7	V
Package Thermal Resistance (SOT-26)	250	°C/W
Maximum Junction Temperature	150	°C
Operating Temperature Range	-40 to 85	°C
Storage Temperature Range	-65 to 150	°C
Lead Temperature (Soldering, 10sec.)	260	°C
ESD Capability, HBM (Human Body Model)	3	kV
ESD Capability, MM (Machine Model)	250	V

Recommended Operation Conditions (Note 2)

11000 million de la contaction (11010 2)						
Parameter	Value	Unit				
Supply Voltage, VDD	10 to 30	V				
Operating Ambient Temperature	-40 to 85	°C				
Maximum Switching Frequency	120K	Hz				



ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C, VDD=16V, if not otherwise noted)$

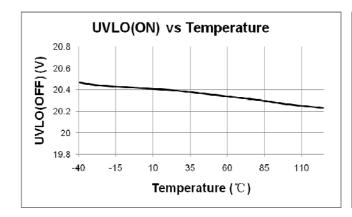
•	V, if not otherwise noted			_	1	I	
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit	
	Supply Voltage (VDD) Section						
I_Startup	VDD Start up Current	VDD =UVLO(ON)-1V,		2	20	uA	
		Measure current into VDD					
I_VDD_Op	Operation Current	V_{FB} =1V,CL=0.5nF,		1	1.5	mA	
		VDD=20V					
UVLO(ON)	VDD Under Voltage		19	20.5	22	V	
	Lockout Exit (Startup)						
UVLO(OFF)	VDD Under Voltage		8.5	9.5	10.5	V	
	Lockout Enter						
VDD_OVP	VDD Over Voltage		31	33	35	V	
	Protection trigger						
V _{DD} _Clamp	VDD Zener Clamp	$I(V_{DD}) = 7 \text{ mA}$	33	35	37	y	
	Voltage						
Feedback Input S					Y	1	
V _{FB} _EA_Ref	Internal Error		1.97	2.0	2.03	V	
	Amplifier(EA)						
	reference input		A				
V _{FB} _Short	Output Short Circuit			1.35		V	
	Threshold					_	
T _{FB} _Short	Output Short Circuit			18		mSec	
	Debounce Time	•	Y				
V _{FB} _DEM	Demagnetization			75		mV	
	comparator threshold						
T _{min} _OFF	Minimum OFF time	X		2		uSec	
T OFF	Marriago of the s			2			
T _{max} _OFF	Maximum OFF time	4 }		3		mSec	
I _{Cable} _max	Max Cable			55		uA	
Gabio_	compensation current						
Current Sense Input Section (CS Pin)							
T blanking	CS Input Leading			500		nSec	
_ 3	Edge Blanking Time						
T _D OC	Over Current	CL=0.5nF at GATE,		100		nSec	
- <u>-</u>	Detection and Control	,					
	Delay						
Constant Current Section (CC Pin)							
V_CC_ref	Internal CC reference		490	500	510	mV	
Gate Drive Outpu							
VOL	Output Low Level	lo = 20 mA (sink)			1	V	
VOH	Output High Level	lo = 20 mA (source)	7.5			V	
VG_Clamp	Output Clamp Voltage	VDD=24V		16		V	
_ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	اميرما		1	1	1	İ	
	Level					-	
Tr	Output Rising Time Output Falling Time	CL = 0.5nF CL =0.5nF		700 35		nSec nSec	

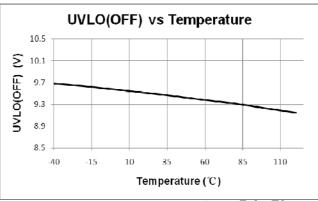
Note 1. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

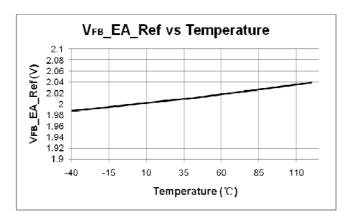
Note 2. The device is not guaranteed to function outside its operating conditions.

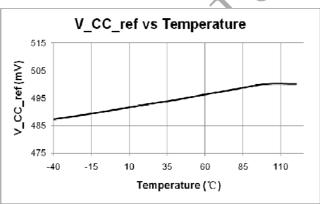


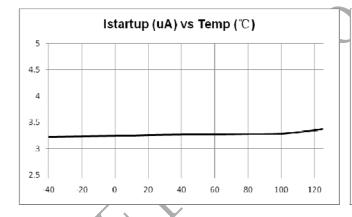
CHARACTERIZATION PLOTS

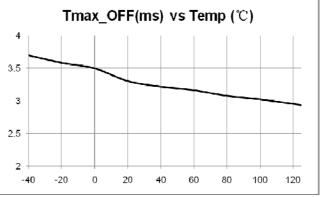














OPERATION DESCRIPTION

SF6771S is a high performance, multi mode controlled, highly integrated QR (Quasi Resonant) Primary Side Regulation (PSR) controller. The built-in high precision CV/CC control with high level protection features make it very suitable for offline small power converter applications.

◆ Startup Current and Startup Control

Startup current of SF6771S is designed to be very low (typically 2uA) so that VDD could be charged up above UVLO(ON) threshold level and device starts up quickly. A large value startup resistor can therefore be used to minimize the power loss yet reliable startup in application.

♦ Operating Current

The operating current in SF6771S is as small as 1mA (typical). The small operating current results in higher efficiency and reduces the VDD hold-up capacitance requirement..

◆ super-QR/PSR[™] Control

SF6771S uses a proprietary *super-QR/PSRTM* control for high efficiency and low EMI. The IC works in Quasi-Resonant (QR) mode in Constant Current (CC) and Constant Voltage (CV) mode. In this way, the efficiency is boosted and the EMI is reduced greatly. The IC can easily meet EPS level 6 standard.

♦ Constant Current (CC) Regulation

SF6771S can accurately control the output current by the internal current feedback control loop. The output mean current in constant current (CC) mode can be approximately expressed as:

$$I_{CC}(mA) = \frac{N}{2} \times \frac{500(mV)}{Rcs(\Omega)}$$

In the equation above,

N----The turn ratio of primary side winding to secondary side winding.

Rcs--- the sensing resistor connected between the MOSFET source to GND.

♦ Precision CV/CC Performance

In SF6771S, the parameters are trimmed to tight range, which makes the system CC/CV to have less than 5% variation.

♦ Soft Start

SF6771S features an internal soft start that slowly increases the threshold of cycle-by-cycle current limiting comparator during startup sequence. It reduces the stress on the secondary diode during startup. Every startup process is followed by a soft start activation.

Proprietary Cable Voltage Drop Compensation in CV Mode

When it comes to cellular phone charger applications, the battery is located at the end of cable, which causes typically several percentage of voltage drop on the actual battery voltage. SF6771S has a proprietary built-in cable voltage drop compensation block which can provide a constant output voltage at the end of the cable over the entire load range in CV mode.

◆ Leading Edge Blanking (LEB)

Each time the power MOSFET is switched on, a turn-on spike occurs across the sensing resistor. To avoid premature termination of the switching pulse, an internal leading edge blanking circuit is built in. During this blanking period (500ns, typical), the cycle-by-cycle current limiting comparator is disabled and cannot switch off the gate driver. Thus, external RC filter with a small time constant is enough for current sensing.

♦ Minimum and Maximum OFF Time

In SF6771S, a minimum OFF time (typically 2us) is implemented to suppress ringing when GATE is off. The minimum OFF time is necessary in applications where the transformer has a large leakage inductance, particularly at low output voltages or startup. The maximum OFF time in SF6771S is typically 3ms, which provides a large range for frequency reduction. In this way, a low standby power of 70mW can be achieved.

♦ Smart Output Short Protection

The output short circuit protection of conventional PSR system is based on the coupling between auxiliary winding and secondary winding. When output is short, the auxiliary winding cannot provide enough energy to the IC any more. In this way, the system will enter into auto-recovery mode protection. However, the IC may be wrongly supplied if the leakage inductance of the primary winding is large enough.

In SF6771S, if output short circuit occurs, the IC will detect the situation and enter into auto-recovery mode protection.

♦ VDD OVP(Over Voltage Protection)

VDD OVP (Over Voltage Protection) is implemented in SF6771S and it is a protection of auto-recovery mode.

◆ Auto Recovery Mode Protection

As shown in Fig.1, once a fault condition is detected, switching will stop. This will cause VDD to fall because no power is delivered form the auxiliary winding. When VDD falls to UVLO(off) (typical 9.5V), the protection is reset and the operating current reduces to the startup current, which causes VDD to rise, as shown in Fig.1. However, if the fault still exists, the system will experience the above mentioned process. If the



fault has gone, the system resumes normal operation. In this manner, the auto restart can alternatively enable and disable the switching until the fault condition is disappeared.

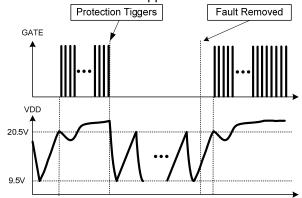


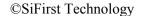
Fig.1

♦ Pin Floating Protection

In SF6771S, if pin floating situation occurs, the IC is designed to have no damage to system.

♦ Soft Gate Drive

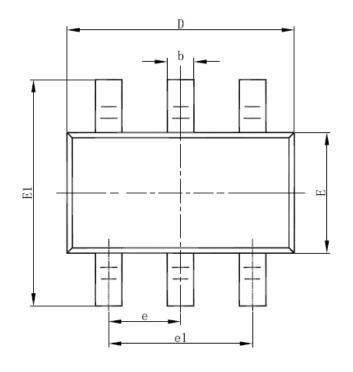
SF6771S has a soft totem-pole gate driver with optimized EMI performance. An internal 16V clamp is added for MOSFET gate protection at higher than expected VDD input.

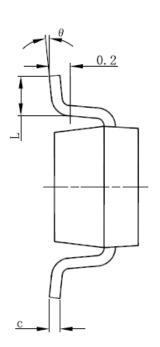


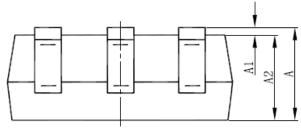


PACKAGE MECHANICAL DATA

SOT-23-6L PACKAGE OUTLINE DIMENSIONS







Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
Α	1.000	1.300	0.039	0.051	
A1	0.000	0.150	0.000	0.006	
A2	1.000	1.200	0.039	0.047	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D'	2.800	3.020	0.110	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.600	3.000	0.102	0.118	
ė	0.950 (BSC)		0.037 (BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	



IMPORTANT NOTICE

SiFirst Technology Nanhai, Ltd (SiFirst) reserves the right to make corrections, modifications, enhancements, improvements and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

SiFirst warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with SiFirst's standard warranty. Testing and other quality control techniques are used to the extent SiFirst deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

SiFirst assumes no liability for application assistance or customer product design. Customers are responsible for their products and applications using SiFirst's components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

Reproduction of SiFirst's information in SiFirst's data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. SiFirst is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of SiFirst's products or services with statements different from or beyond the parameters stated by SiFirst for that product or service voids all express and any implied warranties for the associated SiFirst's product or service and is an unfair and deceptive business practice. SiFirst is not responsible or liable for any such statements.

SiFirst's products are neither designed nor intended for use in military applications. SiFirst will not be held liable for any damages or claims resulting from the use of its products in military applications.

SiFirst's products are not designed to be used as components in devices intended to support or sustain human life. SiFirst will not be held liable for any damages or claims resulting from the use of its products in medical applications.



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Switching Controllers category:

Click to view products by Sifirst manufacturer:

Other Similar products are found below:

LV5725JAZ-AH AP3844CMTR-EI NCP1218AD65R2G NCP1234AD100R2G NCP1244BD065R2G NCP1336ADR2G NCP1587GDR2G NCP6153MNTWG NCP81101BMNTXG NCP81205MNTXG CAT874-80ULGT3 SJE6600 AZ7500BMTR-EI IR35215MTRPBF SG3845DM NCP4204MNTXG NCP6132AMNR2G NCP81102MNTXG NCP81203MNTXG NCP81206MNTXG NX2155HCUPTR UBA2051C IR35201MTRPBF AP3842CMTR-EI NCP1247AD065R2G NCP1015ST65T3G NCP1240AD065R2G NCP1240FD065R2G NCP1361BABAYSNT1G NCP1230P100G NCP1612BDR2G NX2124CSTR SG2845M NCP1366BABAYDR2G NCP81101MNTXG TEA19362T/IJ NCP81174NMNTXG NCP4308DMTTWG NCP4308DMNTWG NCP4308AMTTWG NCP1366AABAYDR2G NCP1256ASN65T1G NCP1251FSN65T1G NCP1246BLD065R2G MB39A136PFT-G-BND-EREI NCP1256BSN100T1G LV5768V-A-TLM-E NCP1365AABCYDR2G IR35204MTRPBF MCP1633T-E/MG